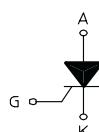
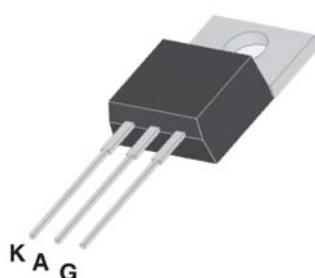


STANDARD SCR

TO220-AB



On-State Current **Gate Trigger Current**
 12 Amp 0.5 mA to 25 mA

Off-State Voltage
 200 V ÷ 800 V

These series of **Silicon Controlled Rectifier** use a high performance PNPN technology.

These parts are intended for general purpose applications where high gate sensitivity is required.

Absolute Maximum Ratings, according to IEC publication No. 134

SYMBOL	PARAMETER	CONDITIONS	Value	Unit
$I_{T(RMS)}$	On-state Current	180° Conduction Angle, $T_c = 110^\circ C$	12	A
$I_{T(AV)}$	Average On-state Current	Half Cycle, $\Theta = 180^\circ$, $T_c = 110^\circ C$	8	A
I_{TSM}	Non-repetitive On-State Current	Half Cycle, 60 Hz	154	A
I_{TSM}	Non-repetitive On-State Current	Half Cycle, 50 Hz	140	A
I^2t	Fusing Current	$t_p = 10ms$, Half Cycle	98	A^2s
I_{GM}	Peak Gate Current	20 μs max.	4	A
P_{GM}	Peak Gate Dissipation	20 μs max.	10	W
$P_{G(AV)}$	Gate Dissipation	20ms max.	1	W
T_j	Operating Temperature		(-40 to +125)	°C
T_{stg}	Storage Temperature		(-40 to +150)	°C
T_{sld}	Soldering Temperature	10s max.	260	°C
V_{RGM}	Reverse Gate Voltage		5	V

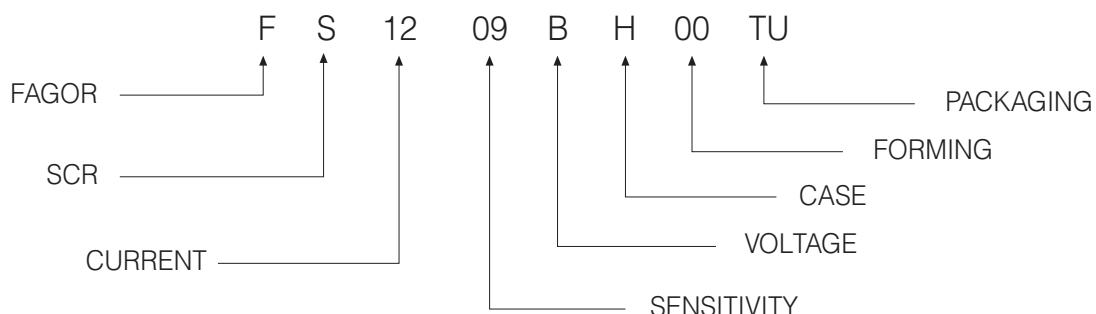
SYMBOL	PARAMETER	CONDITIONS	VOLTAGE						Unit
			B	D	E	M	S	N	
V_{DRM}	Repetitive Peak Off State Voltage	$R_{GK} = 1 k\Omega$	200	400	500	600	700	800	V
V_{RRM}									

STANDARD SCR

Electrical Characteristics

SYMBOL	PARAMETER	CONDITIONS	SENSITIVITY			Uni
			08	09	10	
I_{GT}	Gate Trigger Current	$V_D = 12 \text{ V}_{DC}$, $R_L = 33\Omega$, $T_j = 25^\circ\text{C}$	MIN MAX	0.5 5	2 15	mA
V_{GT}	Gate Trigger Voltage	$V_D = 12 \text{ V}_{DC}$, $R_L = 33\Omega$, $T_j = 25^\circ\text{C}$	MAX		1.3	V
V_{GD}	Gate Non Trigger Voltage	$V_D = V_{DRM}$, $R_L = 3.3k\Omega$, $R_{GK} = 220\Omega$ $T_j = 125^\circ\text{C}$	MIN		0.2	V
I_H	Holding Current	$I_T = 500 \text{ mA}$,	MAX	15	30	mA
I_L	Latching Current	$I_G = 1.2 \times I_{GT}$	MAX	30	60	mA
dV / dt	Critical Rate of Voltage Rise	$V_D = 0.67 \times V_{DRM}$, Gate open $T_j = 125^\circ\text{C}$	MIN	50	200	$\text{V}/\mu\text{s}$
dl / dt	Critical Rate of Current Rise	$I_G = 2 \times I_{GT}$ $Tr \leq 100 \text{ ns}$, $f = 60 \text{ Hz}$, $T_j = 125^\circ\text{C}$	MIN		50	$\text{A}/\mu\text{s}$
V_{TM}	On-state Voltage	at $I_T = 24 \text{ Amp}$, $t_p = 380 \mu\text{s}$, $T_j = 25^\circ\text{C}$	MAX		1.6	V
V_{t0}	Threshold Voltage	$T_j = 125^\circ\text{C}$	MAX		0.80	V
r_d	Dynamic resistance	$T_j = 125^\circ\text{C}$	MAX		30	$\text{m}\Omega$
I_{DRM} / I_{RRM}	Off-State Leakage Current	$V_D = V_{DRM}$, $R_{GK} = 1k\Omega$ $ T_j = 125^\circ\text{C}$ $V_R = V_{RRM}$, $ T_j = 25^\circ\text{C}$	MAX MAX		2 5	mA μA
$R_{th(j-c)}$	Thermal Resistance Junction-Case for DC	for AC 360 ° conduction angle			1.3	$^\circ\text{C}/\text{W}$
$R_{th(j-a)}$	Thermal Resistance Junction-Amb for DC	$S = 1 \text{ cm}^2$			60	$^\circ\text{C}/\text{W}$

PART NUMBER INFORMATION



STANDARD SCR

Fig. 1: Maximum average power dissipation versus average on-state current.

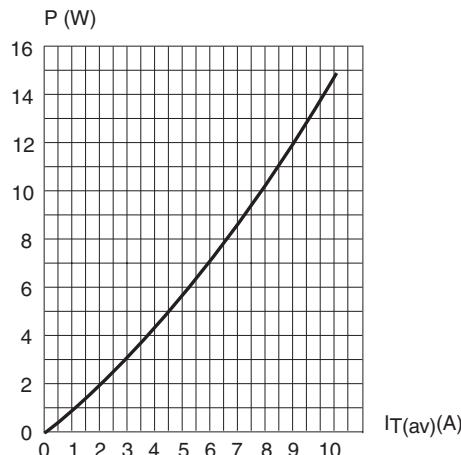


Fig. 3: Relative variation of thermal impedance junction to case versus pulse duration.

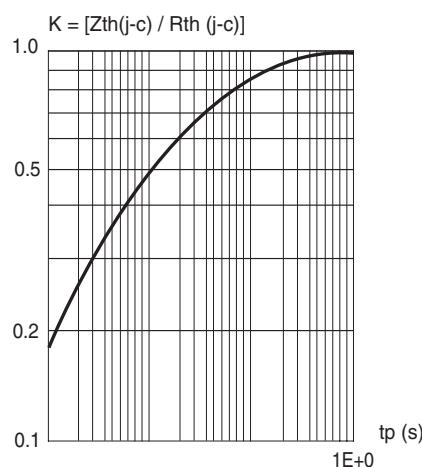


Fig. 5: Non repetitive surge peak on-state current versus number of cycles.

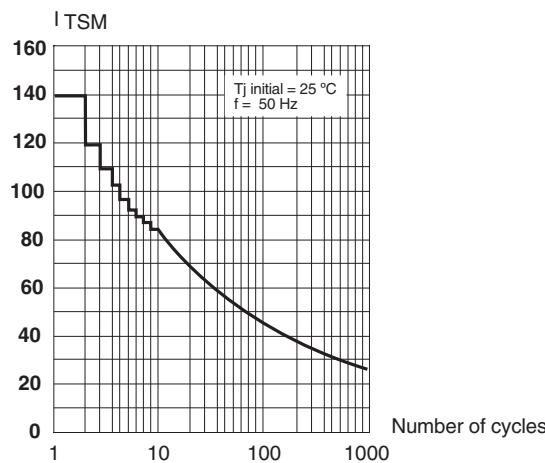


Fig. 2: Average and D.C. on-state current versus case temperature.

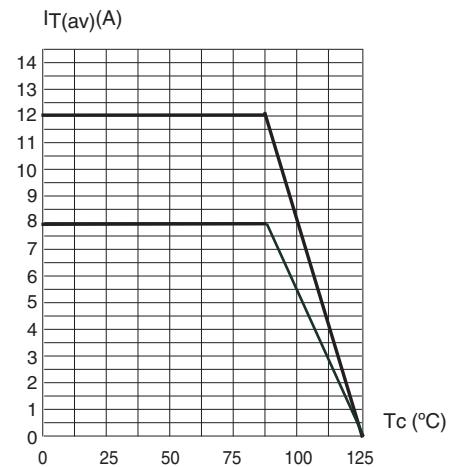


Fig. 4: Relative variation of gate trigger current, holding and latching current versus junction temperature.

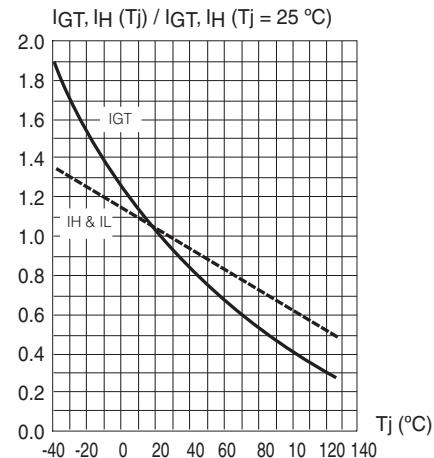
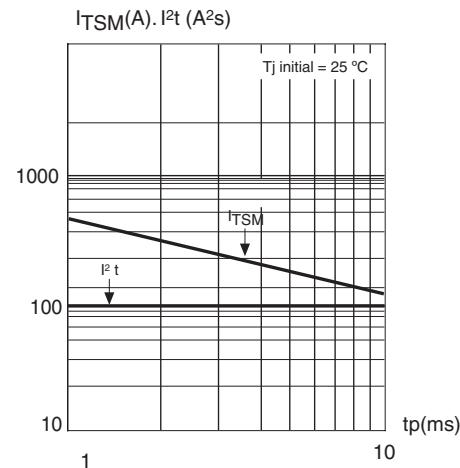
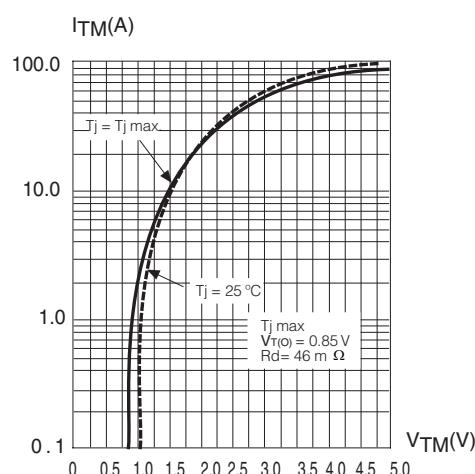
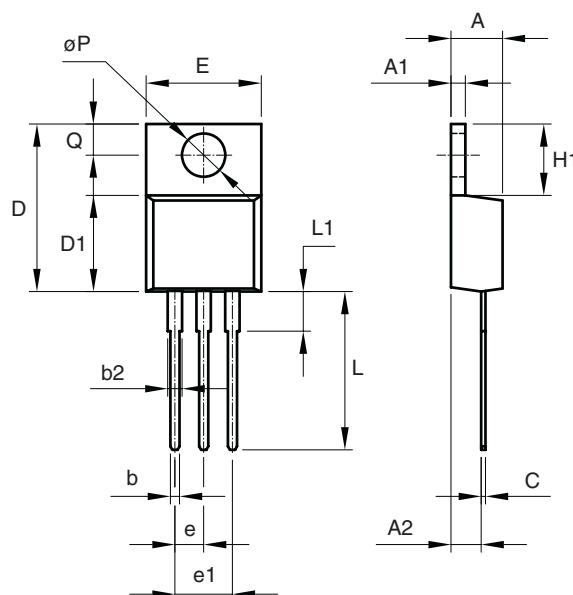


Fig. 6: Non repetitive surge peak on-state current for a sinusoidal pulse with width: $tp < 10$ ms, and corresponding value of I^2t .



STANDARD SCR

Fig. 7: On-state characteristics (maximum values).


PACKAGE MECHANICAL DATA
TO-220AB


REF.	DIMENSIONS	
	Milimeters	
	Min.	Max.
A	4.47	4.67
A1	1.17	1.37
A2	2.52	2.82
b	0.71	0.91
b2	1.17	1.37
c	0.31	0.53
D	14.65	15.35
D1	8.50	8.90
E	10.01	10.36
e	2.51	2.57
e1	4.98	5.18
H1	6.15	6.45
L	13.40	13.96
L1	3.56	3.96
P	3.735	3.935
Q	2.59	2.89

Mounting Torque
1 N.m

(*) Limiting values and life support applications, see Web page.

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